

**AMENDMENTS TO THE CLAIMS**

1. (Canceled)
2. (Canceled)
3. (Canceled)
4. (Canceled)
5. (Canceled)
6. (Currently Amended) ~~The A light detecting element of claim 3, comprising:~~  
~~formed in a semiconductor device, the light detecting element comprising:~~  
~~a photosensitive unit for receiving light irradiated from a light source, said~~  
~~photosensitive unit generating electrons and holes, each of which the number varies~~  
~~with quantity of light received at the photosensitive unit;~~  
~~a carrier separation unit with a separation control electrode, said carrier~~  
~~separation unit separating the electrons and holes generated at said photosensitive unit~~  
~~into object carriers and non-object carriers according to control of electric potential~~  
~~applied to the separation control electrode, said object carriers being one of the~~  
~~electrons and holes, said non-object carriers being another of the electrons and holes;~~  
~~a recombination unit with a recombination control electrode, said recombination~~  
~~unit stimulating recombination between the object carriers generated at said~~  
~~photosensitive unit in a light period and the non-object carriers generated at said~~  
~~photosensitive unit in an extinction period according to control of electric potential~~  
~~applied to the recombination control electrode, said light period being a period of time~~  
~~that said light source is operated, said extinction period being a period of time that said~~  
~~source is extinguished;~~  
~~an output unit for picking out the object carriers which remain after the~~  
~~recombination at said recombination unit;~~

an object carrier holding unit for gathering the object carriers generated at said photosensitive unit to hold the object carriers until the recombination;

a non-object carrier holding unit for gathering the non-object carriers generated at said photosensitive unit to hold the non-object carriers until the recombination,  
wherein said recombination unit stimulates the recombination between the object carriers held at said object carrier holding unit and the non-object carriers held at said non-object carrier holding unit;

an element formation layer of a first conductive type, said element formation layer being formed on a main surface of a semiconductor substrate;

a well region of a second conductive type, said well region being formed at a main surface side within said element formation layer;

a surface electrode which is formed on the main surface of said element formation layer to face at least said well region through an insulating layer, said surface electrode having translucency;

a first holding region of the second conductive type, said first holding region being formed within said well region and at the main surface side of said element formation layer as said object carrier holding unit;

a second holding region of the first conductive type; said second holding region being formed within said first holding region and at the main surface side of said element formation layer as said non-object carrier holding unit; and

a common control electrode as said separation control electrode and said recombination control electrode, said common control electrode being located to face said second holding region through said insulating layer, said common control electrode having translucency,

wherein said photosensitive unit includes said element formation layer which generates the electrons and holes, and

wherein said recombination unit includes at least one of said first holding region and said second holding region.

7. (Original) The light detecting element of claim 6, further comprising:  
a drain region of the second conductive type, said drain region being provided for disposing of the object carriers from said object carrier holding unit, said drain region being formed at the main surface side within said element formation layer and in proximity to said well region; and  
a drain electrode which is coupled to said drain region by ohmic coupling, said drain electrode being applied with electric potential so as to dispose of the object carriers from said first holding region to said drain region.

8. (Currently Amended) ~~The A~~ light detecting element of claim 3, comprising:  
formed in a semiconductor device, the light detecting element comprising:  
a photosensitive unit for receiving light irradiated from a light source, said  
photosensitive unit generating electrons and holes, each of which the number varies  
with quantity of light received at the photosensitive unit;  
a carrier separation unit with a separation control electrode, said carrier  
separation unit separating the electrons and holes generated at said photosensitive unit  
into object carriers and non-object carriers according to control of electric potential  
applied to the separation control electrode, said object carriers being one of the  
electrons and holes, said non-object carriers being another of the electrons and holes;  
a recombination unit with a recombination control electrode, said recombination  
unit stimulating recombination between the object carriers generated at said  
photosensitive unit in a light period and the non-object carriers generated at said  
photosensitive unit in an extinction period according to control of electric potential  
applied to the recombination control electrode, said light period being a period of time  
that said light source is operated, said extinction period being a period of time that said  
source is extinguished;  
an output unit for picking out the object carriers which remain after the  
recombination at said recombination unit;  
an object carrier holding unit for gathering the object carriers generated at said  
photosensitive unit to hold the object carriers until the recombination;

a non-object carrier holding unit for gathering the non-object carriers generated at said photosensitive unit to hold the non-object carriers until the recombination, wherein said recombination unit stimulates the recombination between the object carriers held at said object carrier holding unit and the non-object carriers held at said non-object carrier holding unit;

an element formation layer of a first conductive type, said element formation layer being formed on a main surface of a semiconductor substrate;

a well region of a second conductive type, said well region being formed at a main surface side within said element formation layer as said object carrier holding unit;

a surface electrode which is formed on the main surface of said element formation layer to face at least said well region through an insulating layer, said surface electrode having translucency;

a holding region of the first conductive type, said holding region being formed within said well region and at the main surface side of said element formation layer as said non-object carrier holding unit; and

a common control electrode as said separation control electrode and said recombination control electrode, said common control electrode being located to face a part of said holding region through said insulating layer, said common control electrode having translucency;

wherein said photosensitive unit includes said element formation layer which generates the electrons and holes, and

wherein said recombination unit includes at least one of inside and outside of said holding region within said well region.

9. (Currently Amended) The A light detecting element of claim 3, comprising: formed in a semiconductor device, the light detecting element comprising:

a photosensitive unit for receiving light irradiated from a light source, said photosensitive unit generating electrons and holes, each of which the number varies with quantity of light received at the photosensitive unit;

a carrier separation unit with a separation control electrode, said carrier separation unit separating the electrons and holes generated at said photosensitive unit

into object carriers and non-object carriers according to control of electric potential applied to the separation control electrode, said object carriers being one of the electrons and holes, said non-object carriers being another of the electrons and holes;  
a recombination unit with a recombination control electrode, said recombination unit stimulating recombination between the object carriers generated at said photosensitive unit in a light period and the non-object carriers generated at said photosensitive unit in an extinction period according to control of electric potential applied to the recombination control electrode, said light period being a period of time that said light source is operated, said extinction period being a period of time that said source is extinguished;

an output unit for picking out the object carriers which remain after the recombination at said recombination unit;

an object carrier holding unit for gathering the object carriers generated at said photosensitive unit to hold the object carriers until the recombination;

a non-object carrier holding unit for gathering the non-object carriers generated at said photosensitive unit to hold the non-object carriers until the recombination, wherein said recombination unit stimulates the recombination between the object carriers held at said object carrier holding unit and the non-object carriers held at said non-object carrier holding unit;

an element formation layer of a second conductive type, said element formation layer being formed on a main surface of a semiconductor substrate of the second conductive type through an intermediate layer of a first conductive type;

a well region of the second conductive type, said well region being formed at a main surface side within said element formation layer as said object carrier holding unit;

a surface electrode which is formed on the main surface of said element formation layer to face at least said well region through an insulating layer, said surface electrode having translucency;

a holding region of the first conductive type, said holding region being formed within said well region and at the main surface side of said element formation layer as said non-object carrier holding unit; and

a common control electrode as said separation control electrode and said recombination control electrode, said common control electrode being located to face a part of said holding region through said insulating layer, said common control electrode having translucency,

wherein said photosensitive unit includes said element formation layer which generates the electrons and holes, and

wherein said recombination unit includes at least one of inside and outside of said holding region within said well region.

10. (Previously Presented) The light detecting element of claim 6, further comprising:

a buried layer for increasing potential barrier between said well region and said element formation layer, said buried layer being formed at the bottom of said well region,

wherein said well region within said element formation layer is formed so as to be apart from said substrate.

11. (Previously Presented) The light detecting element of claim 8, further comprising:

a buried layer for increasing potential barrier between said well region and said element formation layer, said buried layer being formed at the bottom of said well region,

wherein said well region within said element formation layer is formed so as to be apart from said substrate.

12. (Previously Presented) The light detecting element of claim 9, further comprising:

a buried layer for increasing potential barrier between said well region and said element formation layer, said buried layer being formed at the bottom of said well region,

wherein said well region within said element formation layer is formed so as to be apart from said substrate.

13. (Withdrawn) A control method of the light detecting element of claim 3, the control method comprising, controlling the electric potential applied to said separation control electrode so as to:

gather the object carriers at said object carrier holding unit while disposing of the non-object carriers in the light period; and

gather the non-object carriers at said non-object carrier holding unit while disposing of the object carriers in the extinction period.

14. (Withdrawn) A control method of the light detecting element of claim 6, the control method comprising:

applying to said common control electrode with electric potential for holding the object carriers and the non-object carriers at said object carrier holding unit and said non-object carrier holding unit respectively; and then

changing the electric potential applied to said common control electrode so that at least one of the object carriers held at said object carrier holding unit and the non-object carriers held at said non-object carrier holding unit moves to be given to the recombination between the object carriers and the non-object carriers.

15. (Withdrawn) A control method of the light detecting element of claim 8, the control method comprising:

applying to said common control electrode with electric potential for holding the object carriers and the non-object carriers at said object carrier holding unit and said non-object carrier holding unit respectively; and then

changing the electric potential applied to said common control electrode so that at least one of the object carriers held at said object carrier holding unit and the non-object carriers held at said non-object carrier holding unit moves to be given to the recombination between the object carriers and the non-object carriers.

16. (Withdrawn) A control method of the light detecting element of claim 9, the control method comprising:

applying to said common control electrode with electric potential for holding the object carriers and the non-object carriers at said object carrier holding unit and said non-object carrier holding unit respectively; and then

changing the electric potential applied to said common control electrode so that at least one of the object carriers held at said object carrier holding unit and the non-object carriers held at said non-object carrier holding unit moves to be given to the recombination between the object carriers and the non-object carriers.

17. (Withdrawn) A control method of the light detecting element of claim 8, the control method comprising:

applying to said common control electrode with electric potential for holding the object carriers and the non-object carriers at said object carrier holding unit and said non-object carrier holding unit respectively; and then

changing the electric potential applied to said common control electrode at plural times so that the recombination is stimulated between the object carriers and the non-object carriers by:

making the object carriers move back and forth between inside and outside of said holding region within said well region; and also

making the non-object carriers move back and forth between parts facing and not facing said common control electrode within said holding region.

18. (Withdrawn) A control method of the light detecting element of claim 9, the control method comprising:

applying to said common control electrode with electric potential for holding the object carriers and the non-object carriers at said object carrier holding unit and said non-object carrier holding unit respectively; and then

changing the electric potential applied to said common control electrode at plural times so that the recombination is stimulated between the object carriers and the non-object carriers by:

making the object carriers move back and forth between inside and outside of said holding region within said well region; and also

making the non-object carriers move back and forth between parts facing and not facing said common control electrode within said holding region.

19. (Withdrawn) A control method of the light detecting element of claim 8, the control method comprising:

controlling the electric potential applied to each of said surface electrode, said common control electrode and said substrate so as to:

gather the non-object carriers at said holding region while disposing of the object carriers in the extinction period; and also

gather the object carriers at said holding region while disposing of the non-object carriers in the light period.

20. (Withdrawn) A control method of the light detecting element of claim 9, the control method comprising:

controlling the electric potential applied to each of said surface electrode, said common control electrode and said substrate so as to:

gather the non-object carriers at said holding region while disposing of the object carriers in the extinction period; and also

gather the object carriers at said holding region while disposing of the non-object carriers in the light period.

21. (Withdrawn) A control method of the light detecting element of claim 14, the control method comprising:

reversing polarity between each electric potential applied to said surface electrode and said common control electrode and the electric potential applied to said substrate, in a state for gathering the object carriers during the light period and a state for gathering the non-object carriers during the extinction period;

reversing polarity of the electric potential applied to said common control electrode at plural times in a state for stimulating the recombination between the object

carriers and the non-object carriers in at least one of the light period and the extinction period; and

    picking out the object carriers remained at said well region after the recombination.